

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## **SiC Schottky Barrier Diode**

$V_R$	650V		
I <sub>F</sub>	20A		
$Q_{C}$	31nC		

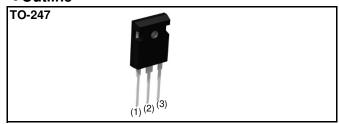
### Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

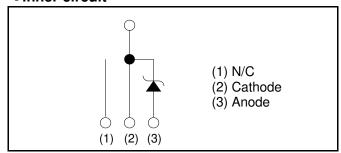
### Construction

Silicon carbide epitaxial planer Shottoky Diode

### Outline



### •Inner circuit



Packaging specifications

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Туре	Packaging	Tube			
	Reel size (mm)	-			
	Tape width (mm)	-			
	Basic ordering unit (pcs)	30			
	Packing code	С			
	Marking	SCS220AE			

### ● Absolute maximum ratings (T<sub>i</sub> = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	$V_{RM}$	650	V	
Reverse voltage (DC)	V <sub>R</sub>	650	V	
Continuous forward current	I <sub>F</sub>	20* <sup>1</sup>	Α	
		71* <sup>2</sup>	Α	
Surge no repetitive forward current	I <sub>FSM</sub>	260* <sup>3</sup>	Α	
		56* <sup>4</sup>	Α	
Repetitive peak forward current	I <sub>FRM</sub>	76* <sup>5</sup>	Α	
Total power disspation	P <sub>D</sub>	130* <sup>6</sup>	W	
Junction temperature	T <sub>j</sub>	175	°C	
Range of storage temperature	T <sub>stg</sub>	-55 to +175	°C	

<sup>\*1</sup>  $T_c$ =128°C \*2 PW=8.3ms sinusoidal,  $T_i$ =25°C \*3 PW=10 $\mu$ s square,  $T_i$ =25°C

<sup>\*4</sup> PW=8.3ms sinusoidal,  $T_j=150$ °C \*5  $T_c=100$ °C,  $T_j=150$ °C, Duty cycle=10%

<sup>\*6</sup>  $T_c=25$ °C

# • Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Lloit
Farameter			Min.	Тур.	Max.	Unit
DC blocking voltage	$V_{DC}$	I <sub>R</sub> =0.4mA	600	-	-	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =20A,T <sub>j</sub> =25°C	-	1.35	1.55	V
		I <sub>F</sub> =20A,T <sub>j</sub> =150°C	-	1.55	-	V
		I <sub>F</sub> =20A,T <sub>j</sub> =175°C	-	1.63	-	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> =600V,T <sub>j</sub> =25°C	-	4	400	μΑ
		V <sub>R</sub> =600V,T <sub>j</sub> =150°C	-	60	-	μΑ
		V <sub>R</sub> =600V,T <sub>j</sub> =175°C	-	140	-	μΑ
Total capacitance	С	V <sub>R</sub> =1V,f=1MHz	-	730	-	pF
		V <sub>R</sub> =600V,f=1MHz	-	74	-	pF
Total capacitive charge	Q <sub>c</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	-	31	-	nC
Switching time	t <sub>c</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	-	19	-	ns

## Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	0.92	1.1	°C/W

### • Electrical characteristic curves

Fig.1 V<sub>F</sub> - I<sub>F</sub> Characteristics

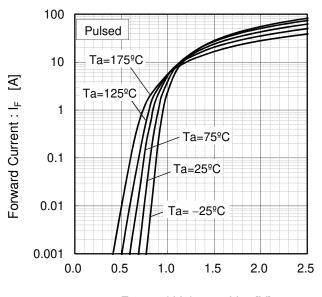
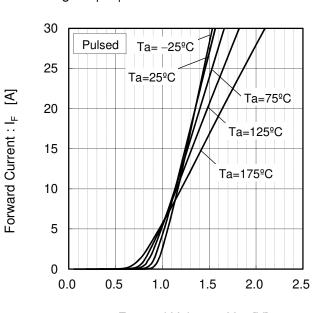


Fig.2 V<sub>F</sub> - I<sub>F</sub> Characteristics



Forward Voltage : V<sub>F</sub> [V]

Forward Voltage : V<sub>F</sub> [V]

Fig.3  $V_R$  -  $I_R$  Characteristics

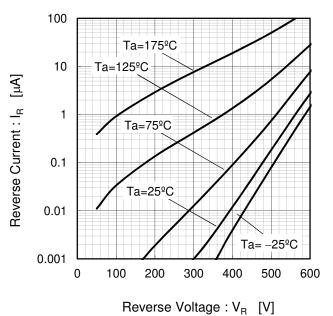
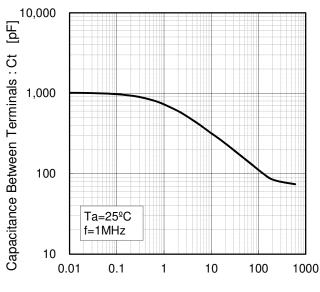


Fig.4 V<sub>R</sub>-Ct Characteristics



Reverse Voltage : V<sub>R</sub> [V]

### • Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

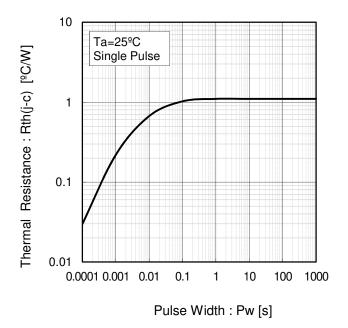
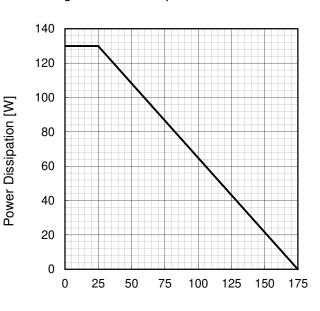


Fig.6 Power Dissipation



Case Temperature : Tc [ºC]

Fig.7 Ip-Tc Derating Curve

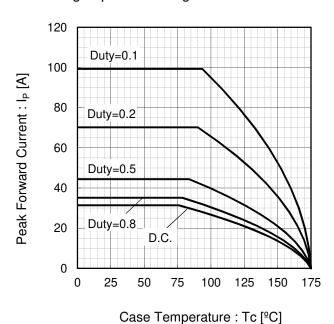
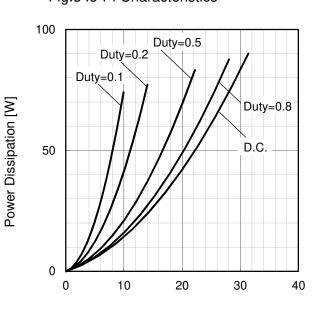


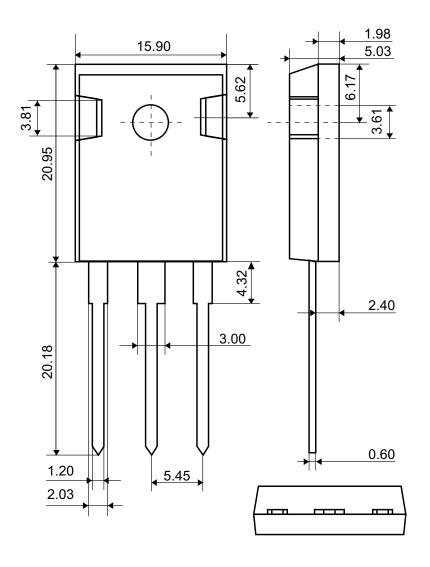
Fig.8 Io-Pf Characteristics



Average Rectified Forward Current : Io [A]

# ● **Dimensions** (Unit: mm)

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